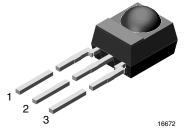


Vishay Semiconductors

IR Receiver Modules for Remote Control Systems



MECHANICAL DATA

ISHAY

Pinning 1 = OUT, 2 = GND, 3 = V_S

FEATURES

- Low supply current
- · Photo detector and preamplifier in one package
- Internal filter for PCM frequency
- · Improved shielding against EMI
- Supply voltage: 2.7 V to 5.5 V
- · Improved immunity against ambient light
- · Insensitive to supply voltage ripple and noise
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

DESCRIPTION

The TSOP48.. series are miniaturized receivers for infrared remote control systems. A PIN diode and a preamplifier are assembled on a lead frame, the epoxy package acts as an IR filter.

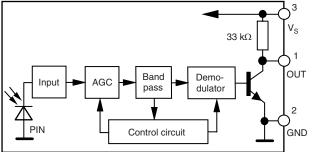
The demodulated output signal can directly be decoded by a microprocessor. The TSOP48.. is the standard IR remote control receiver series, supporting all major data formats.

This component has not been qualified according to automotive specifications.

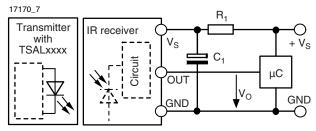
PARTS TABLE				
CARRIER FREQUENCY	STANDARD APPLICATIONS (AGC2/AGC8)			
30 kHz	TSOP4830			
33 kHz	TSOP4833			
36 kHz	TSOP4836			
36.7 kHz	TSOP4837			
38 kHz	TSOP4838			
40 kHz	TSOP4840			
56 kHz	TSOP4856			

BLOCK DIAGRAM

16833_5



APPLICATION CIRCUIT



The external components R1 and C1 are optional to improve the robustnes against electrical overstress (typical values are R1 = 100 Ω , C1 = 0.1 μ F). The output voltage V_o should not be pulled down to a level below 1 V by the external circuit.

The capacitive load at the output should be less than 2 nF.



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ABSOLUTE MAXIMUM RATINGS ⁽¹⁾						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Supply voltage (pin 3)		Vs	- 0.3 to + 6.0	V		
Supply current (pin 3)		I _S	5	mA		
Output voltage (pin 1)		Vo	- 0.3 to 5.5	V		
Voltage at output to supply		V _S - V _O	- 0.3 to (V _S + 0.3)	V		
Output current (pin 1)		Ι _Ο	5	mA		
Junction temperature		Tj	100	°C		
Storage temperature range		T _{stg}	- 25 to + 85	°C		
Operating temperature range		T _{amb}	- 25 to + 85	°C		
Power consumption	$T_{amb} \le 85 \ ^{\circ}C$	P _{tot}	10	mW		
Soldering temperature	$t \le 10$ s, 1 mm from case	T _{sd}	260	°C		

Note

(1) Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect the device reliability.

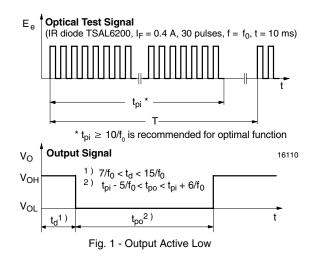
ELECTRICAL AND OPTICAL CHARACTERISTICS (1)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply current (pin 3)	$E_{v} = 0, V_{S} = 5 V$	I _{SD}	0.65	0.85	1.05	mA
	E _v = 40 klx, sunlight	I _{SH}		0.95		mA
Supply voltage		Vs	2.7		5.5	V
Transmission distance	$E_v = 0$, test signal see fig. 1, IR diode TSAL6200, $I_F = 400 \text{ mA}$	d		45		m
Output voltage low (pin 1)	$I_{OSL} = 0.5 \text{ mA}, E_e = 0.7 \text{ mW/m}^2,$ test signal see fig. 1	V _{OSL}			100	mV
Minimum irradiance	$\begin{array}{l} \mbox{Pulse width tolerance:} \\ t_{pi} - 5/f_o < t_{po} < t_{pi} + 6/f_o, \\ \mbox{test signal see fig. 1} \end{array}$	E _{e min.}		0.17	0.35	mW/m ²
Maximum irradiance	$\begin{array}{c} t_{pi} \text{ - } 5/f_o < t_{po} < t_{pi} + 6/f_o, \\ \text{test signal see fig. 1} \end{array}$	E _{e max.}	30			W/m ²
Directivity	Angle of half transmission distance	Φ1/2		± 45		deg

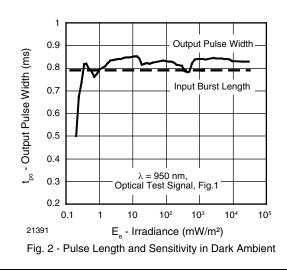
Note

⁽¹⁾ T_{amb} = 25 °C, unless otherwise specified

TYPICAL CHARACTERISTICS

 $T_{amb} = 25$ °C, unless otherwise specified



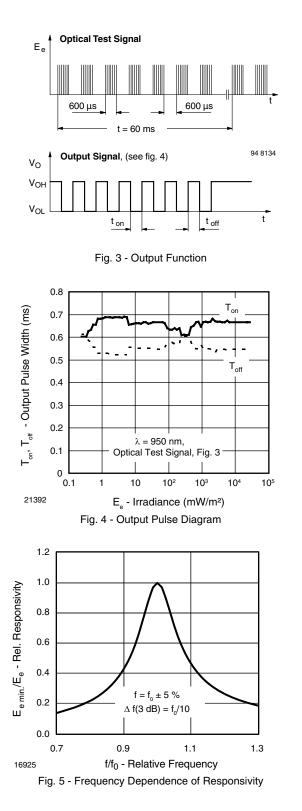


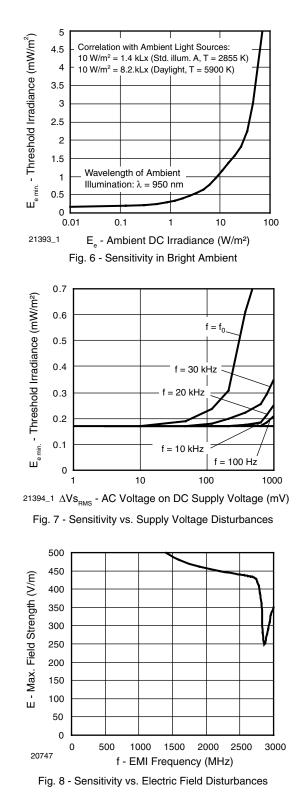


New TSOP48..

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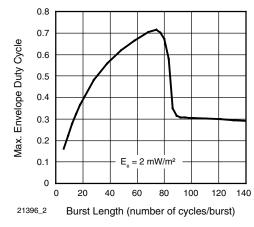


Fig. 9 - Max. Envelope Duty Cycle vs. Burst Length

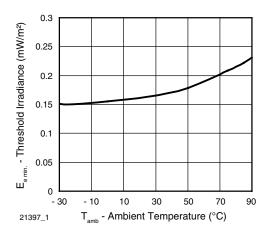


Fig. 10 - Sensitivity vs. Ambient Temperature

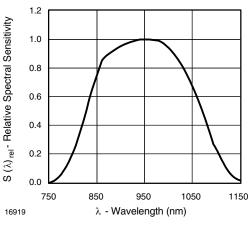
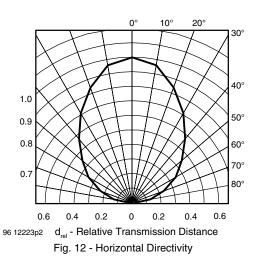


Fig. 11 - Relative Spectral Sensitivity vs. Wavelength



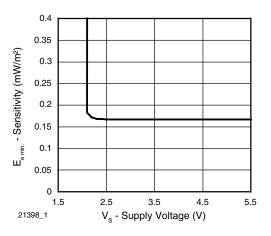


Fig. 13 - Sensitivity vs. Supply Voltage



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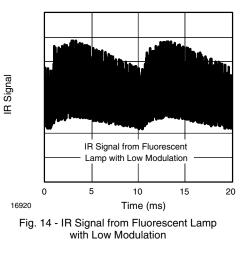
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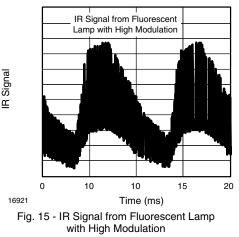
SUITABLE DATA FORMAT

The TSOP48.. series is designed to suppress spurious output pulses due to noise or disturbance signals. Data and disturbance signals can be distinguished by the devices according to carrier frequency, burst length and envelope duty cycle. The data signal should be close to the band-pass center frequency (e.g. 38 kHz) and fulfill the conditions in the table below.

When a data signal is applied to the TSOP48.. in the presence of a disturbance signal, the sensitivity of the receiver is reduced to insure that no spurious pulses are present at the output. Some examples of disturbance signals which are suppressed are:

- DC light (e.g. from tungsten bulb or sunlight)
- · Continuous signals at any frequency
- Modulated IR signals from common fluorescent lamps (example of noise pattern is shown in figure 14 or figure 15)





	TSOP48			
Minimum burst length	10 cycles/burst			
After each burst of length a minimum gap time is required of	10 to 70 cycles ≥ 12 cycles			
For bursts greater than a minimum gap time in the data stream is needed of	70 cycles > 4 x burst length			
Maximum number of continuous short bursts/second	800			
Compatible to NEC code	yes			
Compatible to RC5/RC6 code	yes			
Compatible to Sony code	yes			
Compatible to Thomson 56 kHz code	yes			
Compatible to Mitsubishi code (38 kHz, preburst 8 ms, 16 bit)	yes			
Compatible to Sharp code	yes			
Suppression of interference from fluorescent lamps	Most common disturbance signals are suppressed			

Note

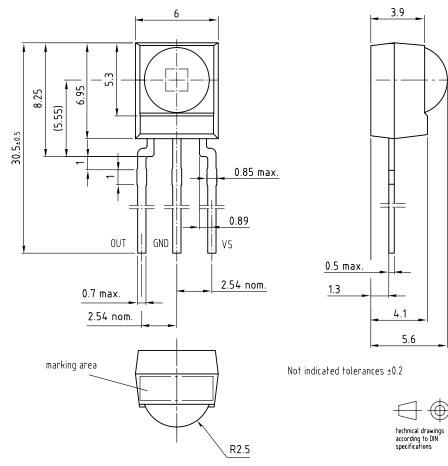
For data formats with short bursts please see the data sheet of TSOP41..

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IR Receiver Modules for Remote Control Systems



PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.550-5169.11-4 Issue: 10; 08.06.04

16003



IR Receiver Modules for Remote Control Systems

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OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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